# NSN 5962-01-251-5930

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# Body Length:

0.960 inches

### Body Width:

Between 0.220 inches and 0.310 inches

### **Body Height:**

0.185 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and bipolar and programmable and w/enable

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

12 input

Case Outline Source And Designator:

D-6 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Prom

# Memory Capacity:

Unknown

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

18 printed circuit

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

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